

# SKKT 15, SKKH 15



**SEMIPACK® 0**

## Thyristor / Diode Modules

**SKKT 15**  
**SKKH 15**

### Features

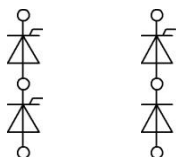
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

### Typical Applications

- DC motor control (e. g. for machine tools)
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

$V_{RSM}$ V	$V_{RRM}, V_{DRM}$ V	$I_{TRMS} = 24$ A (maximum value for continuous operation) $I_{TAV} = 15$ A (sin. 180; $T_c = 75$ °C)	
700	600	SKKT 15/06E	SKKH 15/06E
900	800	SKKT 15/08E	SKKH 15/08E
1300	1200	SKKT 15/12E	SKKH 15/12E
1500	1400	SKKT 15/14E	SKKH 15/14E
1700	1600	SKKT 15/16E	SKKH 15/16E

Symbol	Conditions	Values	Units
$I_{TAV}$	sin. 180; $T_c = 85$ (100) °C	13,5 (9,5)	A
$I_D$	P13A/100; $T_a = 45$ °C; B2 / B6	14 / 17	A
$I_{RMS}$	P13A/100; $T_a = 45$ °C; W1 / W3	21 / 3 x 12	A
$I_{TSM}$	$T_{vj} = 25$ °C; 10 ms	320	A
	$T_{vj} = 125$ °C; 10 ms	280	A
$i^2t$	$T_{vj} = 25$ °C; 8,3 ... 10 ms	510	A <sup>2</sup> s
	$T_{vj} = 125$ °C; 8,3 ... 10 ms	390	A <sup>2</sup> s
$V_T$	$T_{vj} = 25$ °C; $I_T = 75$ A	max. 2,45	V
$V_{T(TO)}$	$T_{vj} = 125$ °C	max. 1,1	V
$r_T$	$T_{vj} = 125$ °C	max. 20	mΩ
$I_{DD}, I_{RD}$	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 8	mA
$t_{gd}$	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
$t_{gr}$	$V_D = 0,67 * V_{DRM}$	1	μs
$(di/dt)_{cr}$	$T_{vj} = 125$ °C	max. 100	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C	max. 1000	V/μs
$t_q$	$T_{vj} = 125$ °C	80	μs
$I_H$	$T_{vj} = 25$ °C; typ. / max.	80 / 150	mA
$I_L$	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	150 / 300	mA
$V_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 3	V
$I_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 100	mA
$V_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
$I_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 5	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	1,6 / 0,8	K/W
	sin. 180; per thyristor / per module	1,7 / 0,9	K/W
	rec. 120; per thyristor / per module	1,8 / 0,9	K/W
$R_{th(c-s)}$	per thyristor / module	0,2 / 0,1	K/W
$T_{vj}$		- 40 ... + 125	°C
$T_{stg}$		- 40 ... + 125	°C
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
$M_s$	to heatsink	1,5 ± 15 %	Nm
$a$		5 * 9,81	m/s <sup>2</sup>
$m$	approx.	50	g
Case	SKKT	A 1	
	SKKH	A 2	



SKKT

SKKH

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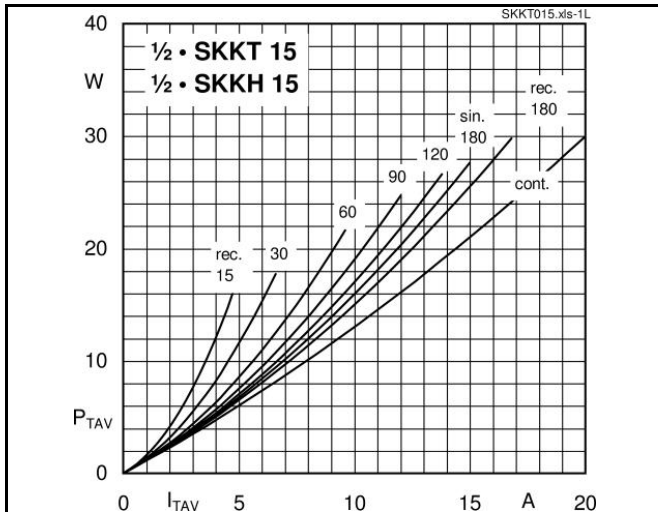


Fig. 1L Power dissipation per thyristor vs. on-state current

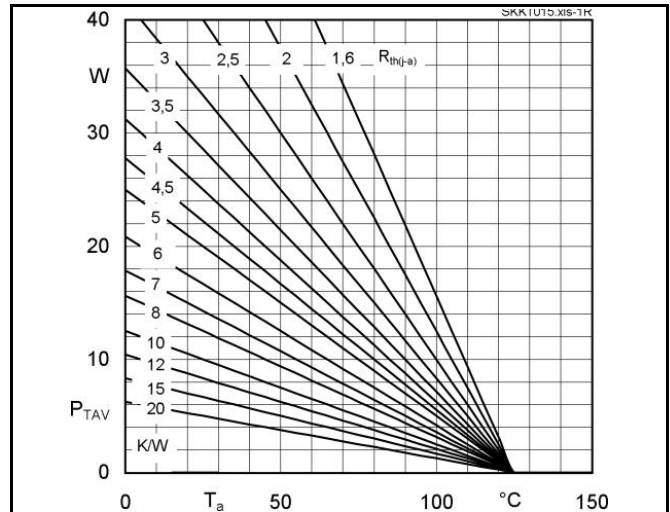


Fig. 1R Power dissipation per thyristor vs. ambient temp.

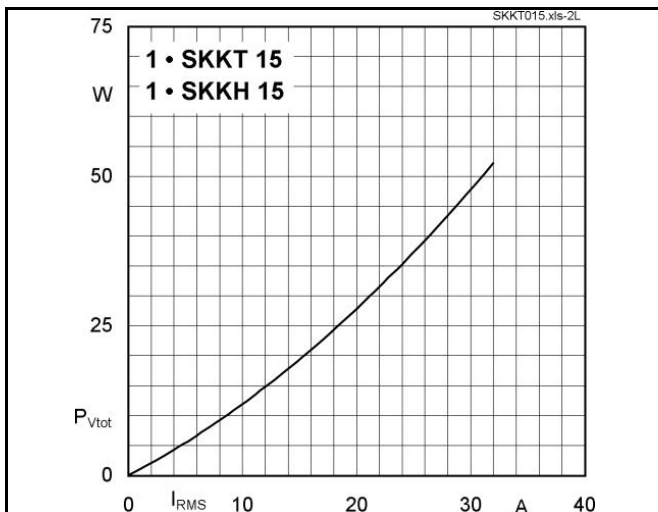


Fig. 2L Power dissipation per module vs. rms current

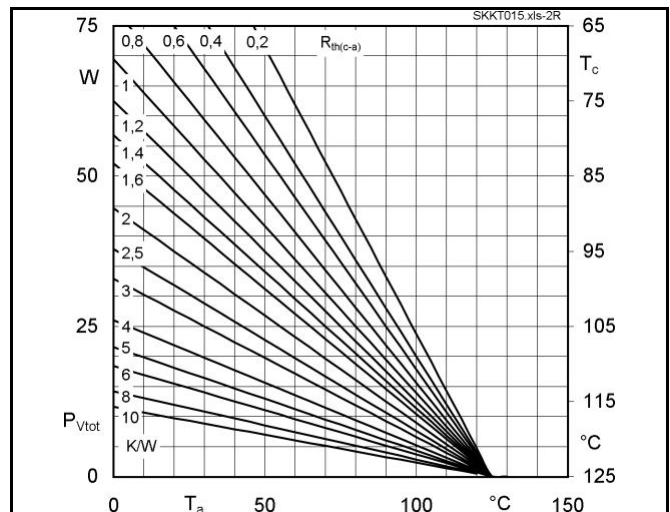


Fig. 2R Power dissipation per module vs. case temp.

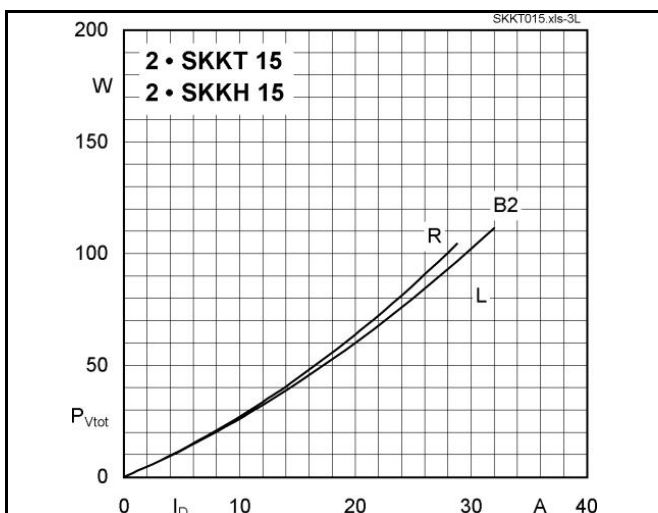


Fig. 3L Power dissipation of two modules vs. direct current

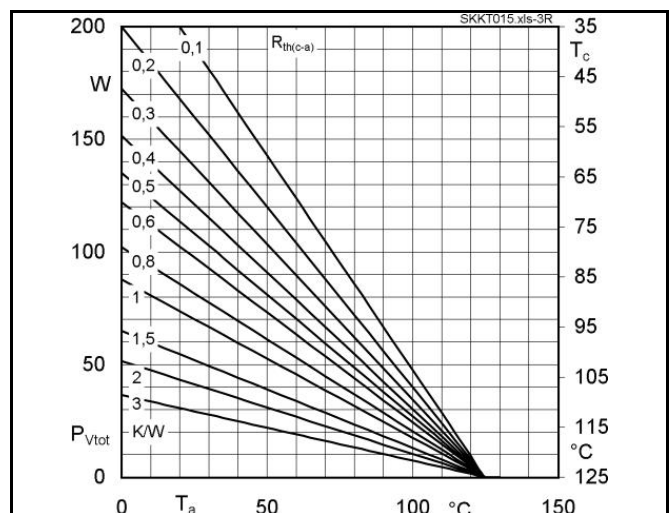


Fig. 3R Power dissipation of two modules vs. case temp.

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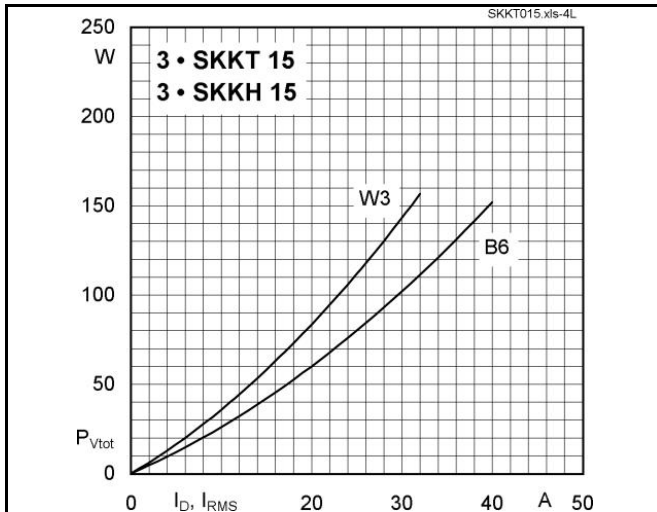


Fig. 4L Power dissipation of three modules vs. direct and rms current

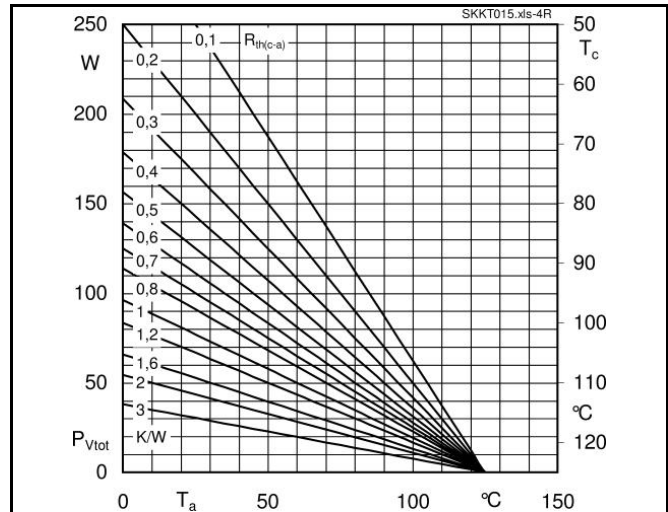


Fig. 4R Power dissipation of three modules vs. case temp.

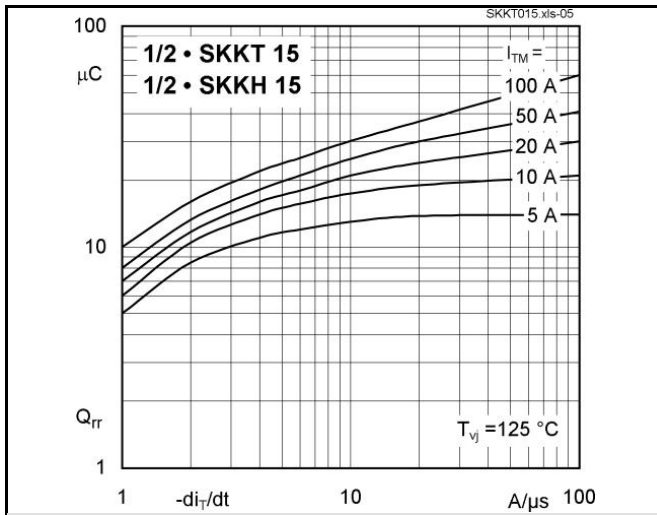


Fig. 5 Recovered charge vs. current decrease

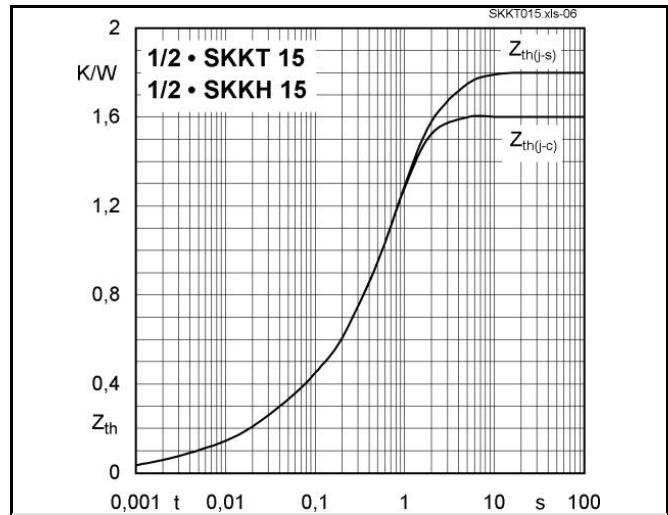


Fig. 6 Transient thermal impedance vs. time

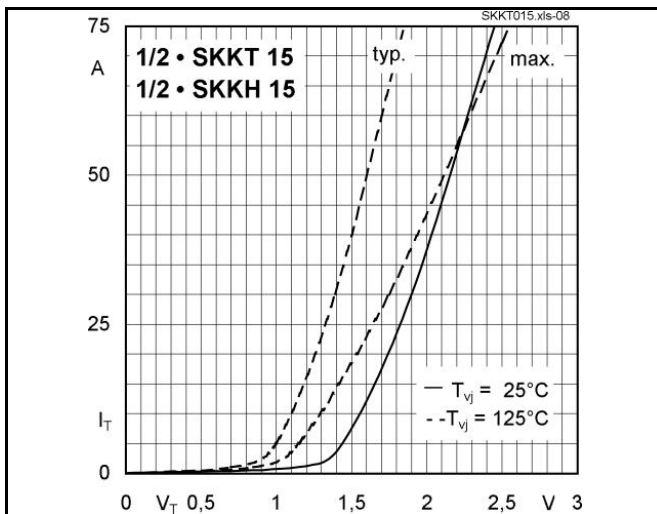


Fig. 7 On-state characteristics

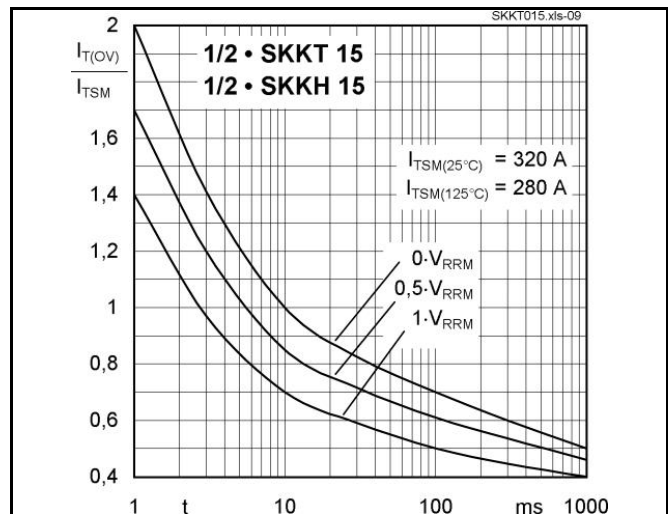
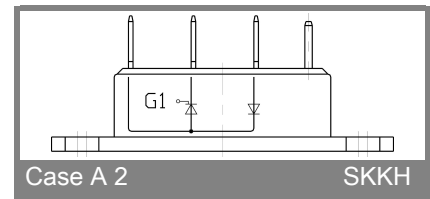
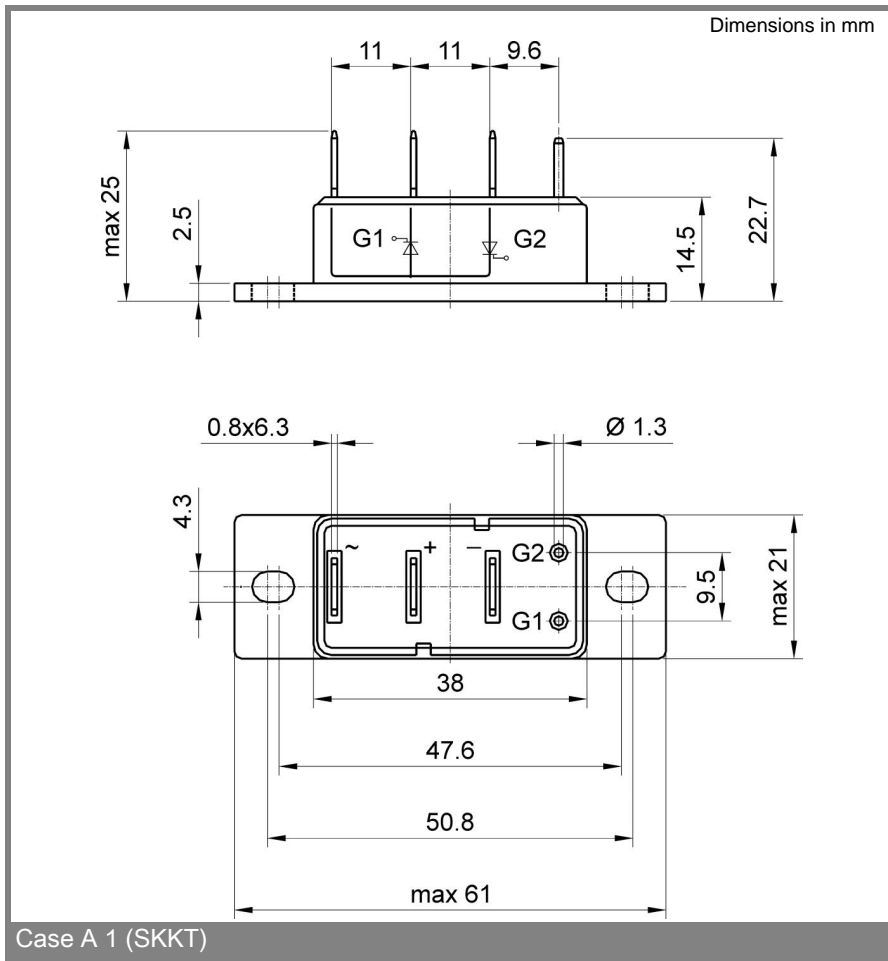
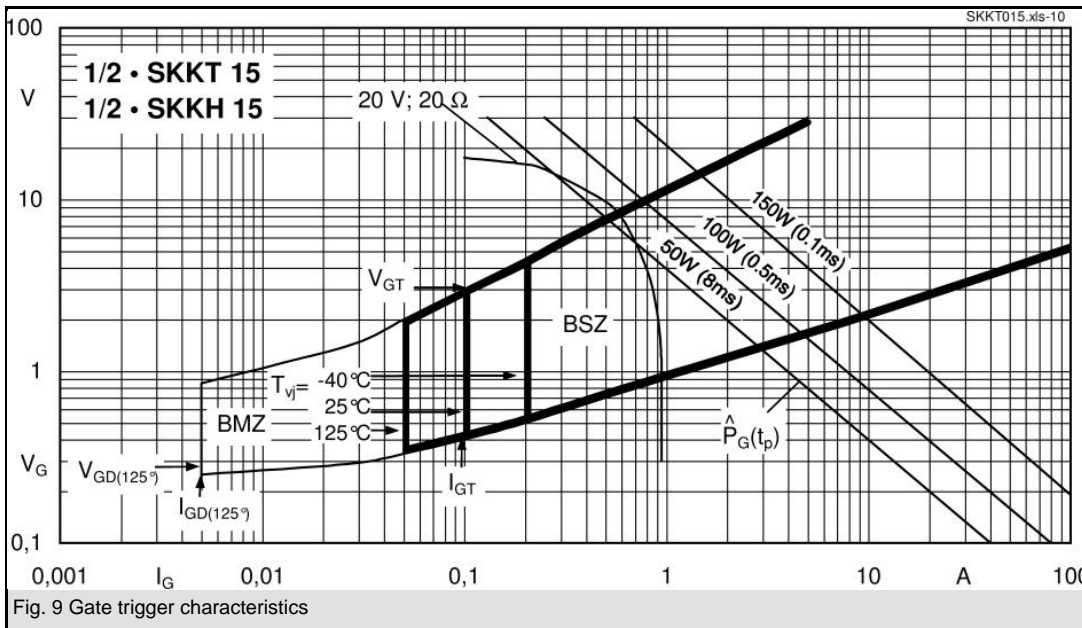


Fig. 8 Surge overload current vs. time

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